

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

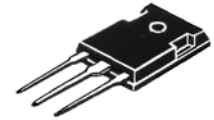
Characteristic	Symbol	S40D90C	S40D100C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	90	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	63	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), $T_C=100^\circ\text{C}$	$I_{F(AV)}$	20 40		A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	40		A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfwave, single phase, 60Hz)	I_{FSM}	300		A
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150		°C

ELECTRICAL CHARACTERISTICS

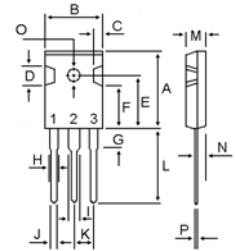
Characteristic	Symbol	S40D90C	S40D100C	Unit
Maximum Instantaneous Forward Voltage ($I_F=20$ Amp $T_C=25^\circ\text{C}$) ($I_F=20$ Amp $T_C=125^\circ\text{C}$)	V_F	0.85 0.75		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C=25^\circ\text{C}$) (Rated DC Voltage, $T_C=125^\circ\text{C}$)	I_R	1.0 80		mA

SCHOTTKY BARRIER RECTIFIERS

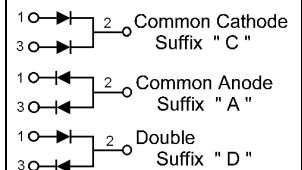
**40 AMPERES
90-100 VOLTS**



TO-3P



DIM	MILLIMETERS	
	MIN	MAX
A	20.63	22.38
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.81	15.22
F	11.72	12.84
G	4.20	4.50
H	1.82	2.46
I	2.92	3.23
J	0.89	1.53
K	5.26	5.66
L	18.50	21.50
M	4.68	5.36
N	2.40	2.80
O	3.25	3.65
P	0.55	0.70



S40D90C Thru S40D100C

FIG-1 FORWARD CURRENT DERATING CURVE

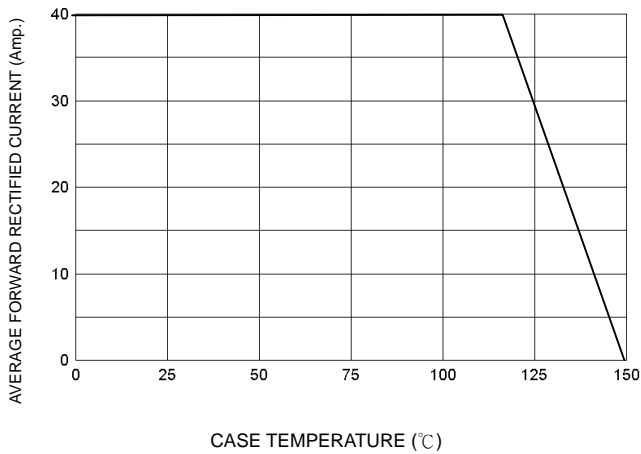


FIG-2 TYPICAL FORWARD CHARACTERISTICS

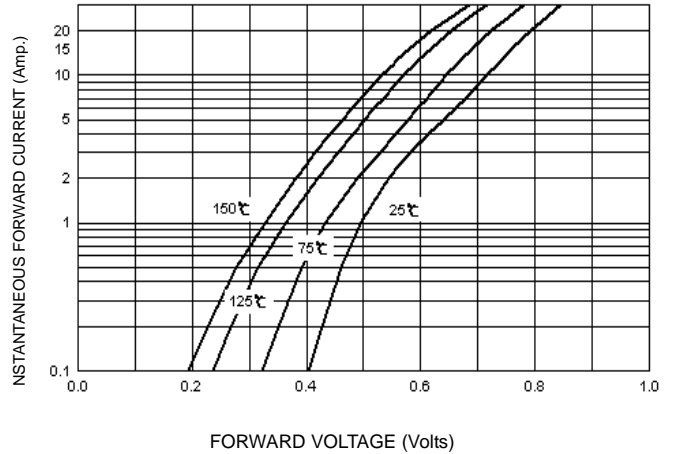


FIG-3 TYPICAL REVERSE CHARACTERISTICS

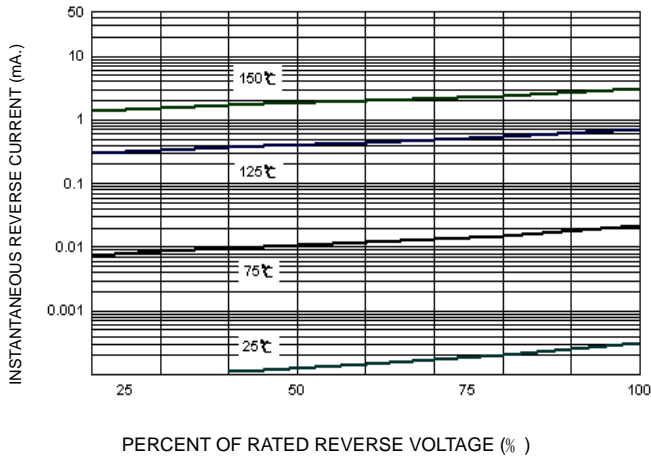


FIG-4 TYPICAL JUNCTION CAPACITANCE

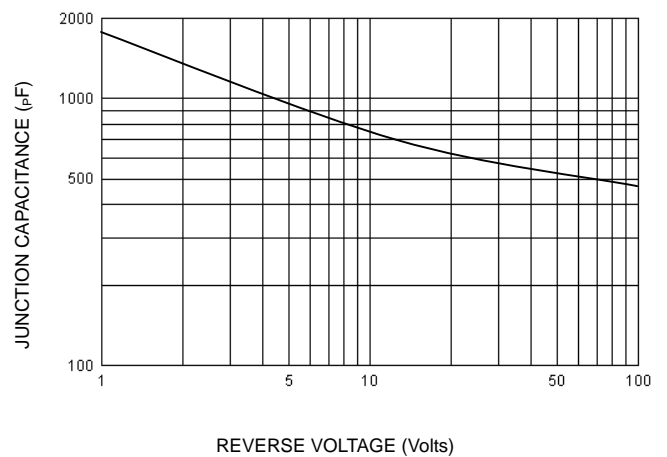
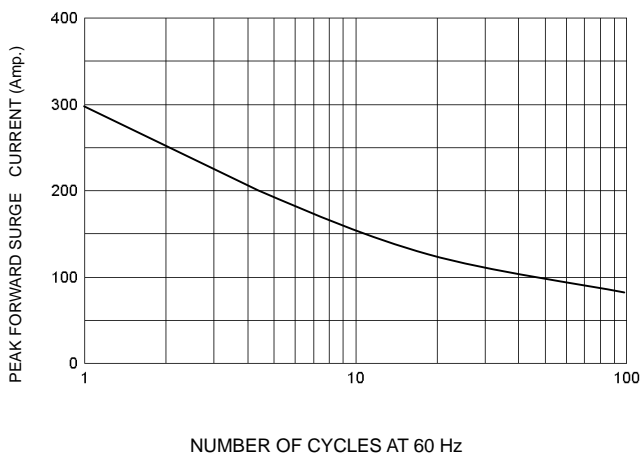


FIG-5 PEAK FORWARD SURGE CURRENT



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